



Si - photodiode with integrated amplifier

JI 447L

JI 448L

**characteristics :**

- ◆ Si-photodiode with integrated low noise JFET-amplifier
- ◆ integrated feedback resistor and capacitor
- ◆ decadic staggered responsivity
- ◆ spectral range VIS and NIR
- ◆ very low offset- and driftparameters
- ◆ high dynamic range
- ◆ single voltage supply
- ◆ low power consumption
- ◆ external sensor pin for reducing responsivity or cut-off-frequency
- ◆ hermetically sealed TO-5 package with lense cap
- ◆ assembly isolated to package
- ◆ replacement type for IPL10500 and IPL10530 from IPL (not pin compatibel)
- ◆ components are in conformity with RoHS and WEEE

applications :

- ◆ common light-/radiation measuring applications
- ◆ detector for measuring of low radiation intensities with high signal to noise level
- ◆ spectroscopy
- ◆ medical diagnostics

maximum ratings :

- ◆ operating voltage +27 V
- ◆ operating temperature range -25 °C ... +85 °C
- ◆ storage temperature range -40 °C ... +100 °C
- ◆ welding temperature (3s) 300 °C

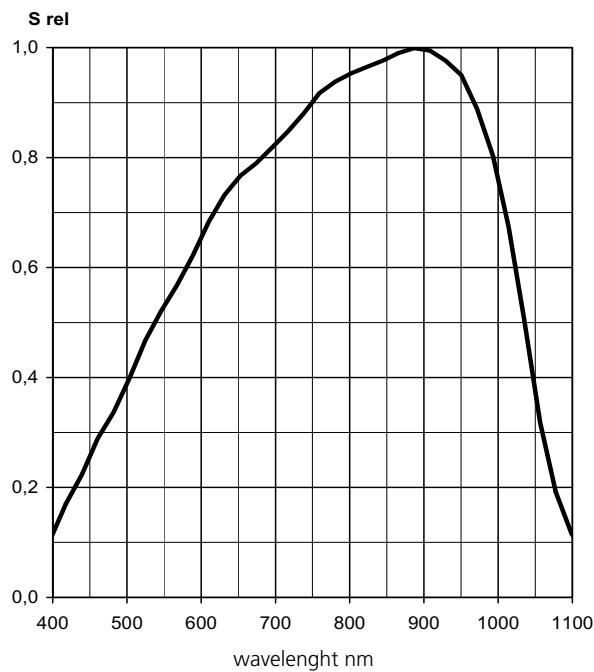
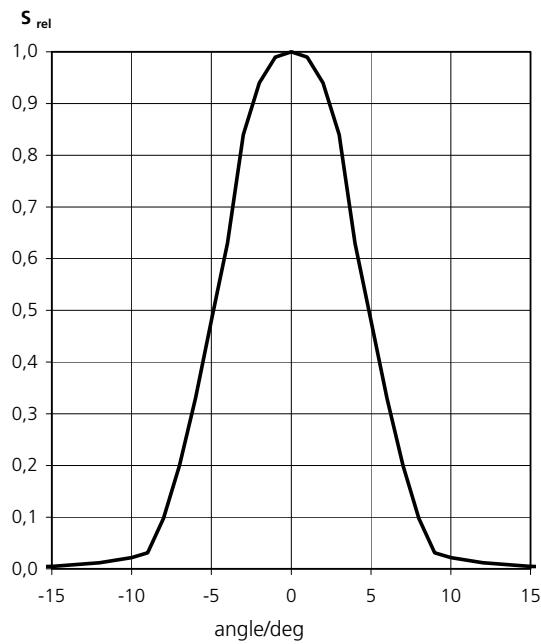
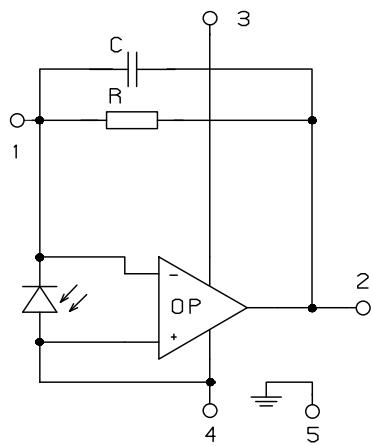
technical data :

common test conditions, as not otherwise specified: $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$
 typ. data, maximum data in brackets

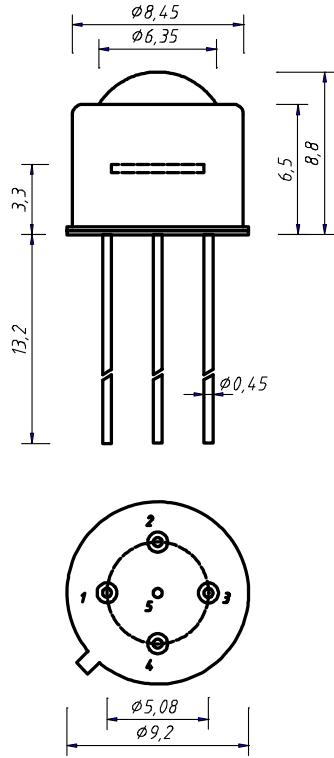
parameter	testcondition	JI 447L	JI 448 L	unit
active area		4,8	4,8	mm^2
feedback resistor		10	100	$\text{M}\Omega$
dark offset voltage	$E = 0 \text{ lx}$	$\pm 0,5 (\pm 2)$	$\pm 0,5 (\pm 2)$	mV
noise voltage	$B = 10 \text{ kHz}$	0,5	0,5	mV_{rms}
spectral range	$S=0,1*S_{\text{max}}$	400...1100	400...1100	nm
max. of spectral responsivity	$S = S_{\text{max}}$	850	850	nm
max. spectral responsivity	$S=S_{\text{max}}$	10	100	mV/nW
rise time		20	50	μs
bandwidth	- 3 dB	15	5	kHz
opening angle	$S=0,5*S_{\text{max}}$	± 5	± 5	Grad
saturation voltage	$R_L = 2 \text{ k}\Omega$	+0,01... +23,90	+0,01... +23,90	V
short current		± 10	± 10	mA
operation voltage	SUNSTAR自动化 http://www.sensor-ic.com/ TEL: 0755-83376389 FAX: 0755-83376126 E-MAIL: szss20@163.com			
current consumption		0,7 (1,0)	0,7 (1,0)	mA

D
A
T
A

S
H
E
E
T

relative spectral responsivity**angle dependence****Internal circuit**

- 1 R_f
- 2 Out
- 3 V_s
- 4 GND
- 5 Case

package dimension**application hints:**

- If an external resistor for reduction of gain is used, please make sure that lenght of connectors is as short as possible to reduce noise and capacative interference.
- If internally adjusted gain is used only, please cut pin „1“.